

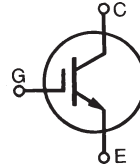
IGBT

Optimized for
switching up to 5KHz

IXGA 12N120A2
IXGP 12N120A2

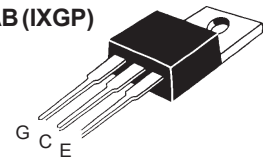
$V_{CES} = 1200\text{ V}$
 $I_{C25} = 24\text{ A}$
 $V_{CE(sat)} = 3.0\text{ V}$

Preliminary data sheet

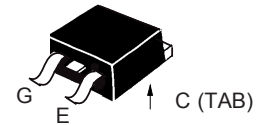


| Symbol | Test Conditions | Maximum Ratings | |
|---|---|--------------------------------------|------------------|
| V_{CES} | $T_J = 25^\circ\text{C to } 150^\circ\text{C}$ | 1200 | V |
| V_{CGR} | $T_J = 25^\circ\text{C to } 150^\circ\text{C}; R_{GE} = 1\text{ M}\Omega$ | 1200 | V |
| V_{GES} | Continuous | ± 20 | V |
| V_{GEM} | Transient | ± 30 | V |
| I_{C25} | $T_C = 25^\circ\text{C}$ | 24 | A |
| I_{C90} | $T_C = 90^\circ\text{C}$ | 12 | A |
| I_{CM} | $T_C = 25^\circ\text{C}, 1\text{ ms}$ | 48 | A |
| SSOA (RBSOA) | $V_{GE} = 15\text{ V}, T_{VJ} = 125^\circ\text{C}, R_G = 100\ \Omega$ Clamped inductive load | $I_{CM} = 24$ @ $0.8 V_{CES}$ | A |
| P_C | $T_C = 25^\circ\text{C}$ | 75 | W |
| T_J | | -55 ... +150 | $^\circ\text{C}$ |
| T_{JM} | | 150 | $^\circ\text{C}$ |
| T_{stg} | | -55 ... +150 | $^\circ\text{C}$ |
| Maximum lead temperature for soldering 1.6 mm (0.062 in.) from case for 10 s | | 300 | $^\circ\text{C}$ |
| M_d | Mounting torque with screw M3 Mounting torque with screw M3.5 | 0.45/4 Nm/lb.in. 0.55/5 Nm/lb.in. | |
| Weight | TO-220 | 4 | g |
| | TO-263 | 2 | g |

TO-220AB (IXGP)



TO-263 AA (IXGA)



Features

- International standard packages
JEDEC TO-220AB and TO-263AA
- Low $V_{CE(sat)}$
- for minimum on-state conduction losses
- MOS Gate turn-on
- drive simplicity

Applications

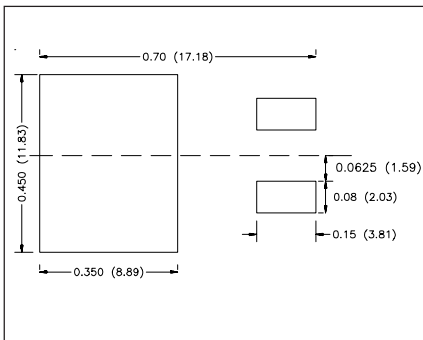
- AC motor speed control
- DC servo and robot drives
- DC choppers
- Uninterruptible power supplies (UPS)
- Switch-mode and resonant-mode power supplies
- Capacitor discharge

Advantages

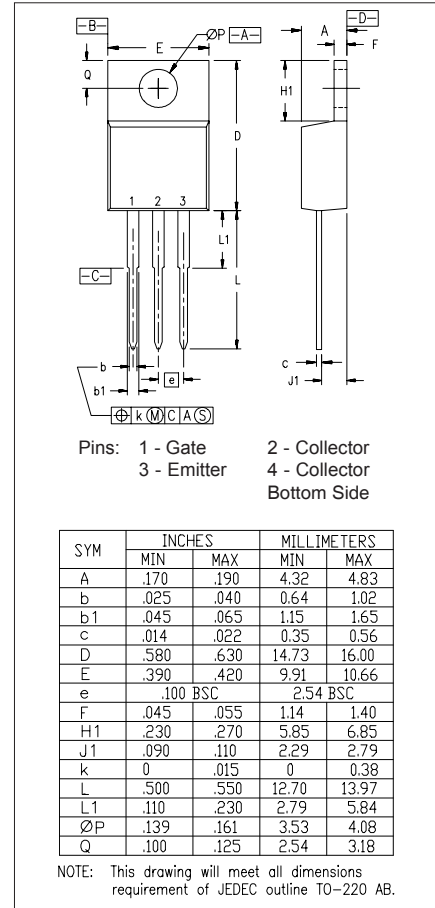
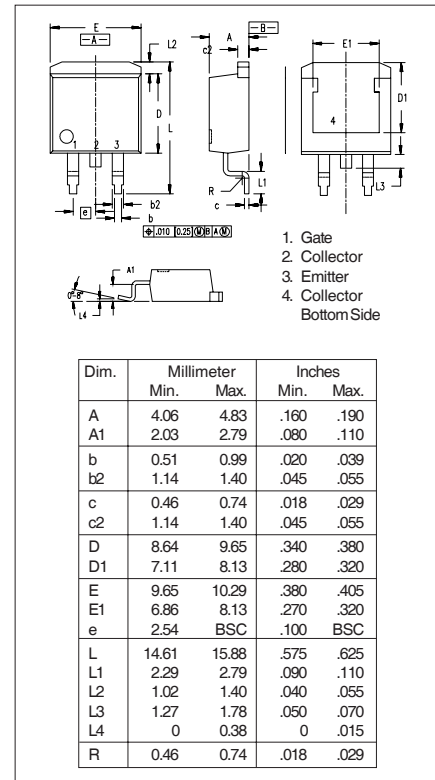
- Easy to mount with one screw
- Reduces assembly time and cost
- High power density

| Symbol | Test Conditions ($T_J = 25^\circ\text{C}$, unless otherwise specified) | Characteristic Values | | |
|---------------|---|---------------------------|------|---------------------|
| | | Min. | Typ. | Max. |
| BV_{CES} | $I_C = 250\ \mu\text{A}, V_{GE} = 0\text{ V}$ | 1200 | | V |
| $V_{GE(th)}$ | $I_C = 250\ \mu\text{A}, V_{CE} = V_{GE}$ | 2.5 | | V |
| I_{CES} | $V_{CE} = V_{CES}$ $V_{GE} = 0\text{ V}$ | $T_J = 25^\circ\text{C}$ | | 25 μA |
| | | $T_J = 125^\circ\text{C}$ | | 250 μA |
| I_{GES} | $V_{CE} = 0\text{ V}, V_{GE} = \pm 20\text{ V}$ | | | $\pm 100\text{ nA}$ |
| $V_{CE(sat)}$ | $I_C = I_{C90}, V_{GE} = 15\text{ V}$ | | 2.4 | 3.0 V |

| Symbol | Test Conditions ($T_J = 25^\circ\text{C}$, unless otherwise specified) | Characteristic Values | | | |
|--------------|---|-----------------------|------|------|----|
| | | Min. | Typ. | Max. | |
| g_{fs} | $I_C = I_{C90}$, $V_{CE} = 10\text{ V}$ Pulse test, $t \leq 300\ \mu\text{s}$, duty cycle $\leq 2\%$ | 4.0 | 7.8 | S | |
| $I_{C(on)}$ | $V_{GE} = 10\text{ V}$, $V_{CE} = 10\text{ V}$ | | 35 | A | |
| C_{ies} | $V_{CE} = 25\text{ V}$, $V_{GE} = 0\text{ V}$, $f = 1\text{ MHz}$ | | 530 | pF | |
| C_{oes} | | | 30 | pF | |
| C_{res} | | | 4 | pF | |
| Q_g | $I_C = I_{C90}$, $V_{GE} = 15\text{ V}$, $V_{CE} = 0.5\text{ V}_{CES}$ | | 24 | nC | |
| Q_{ge} | | | 5.5 | nC | |
| Q_{gc} | | | 8.8 | nC | |
| $t_{d(on)}$ | Inductive load, $T_J = 25^\circ\text{C}$ $I_C = I_{C90}$, $V_{GE} = 15\text{ V}$ $V_{CE} = 960\text{ V}$, $R_G = R_{off} = 100\ \Omega$ Remarks: Switching times may increase for V_{CE} (Clamp) $> 0.8\text{ V}_{CES}$, higher T_J or increased R_G | | 15 | ns | |
| t_{ri} | | | 30 | ns | |
| $t_{d(off)}$ | | | 680 | 1000 | ns |
| t_{fi} | | | 650 | 1000 | ns |
| E_{off} | | | 5.4 | 9.0 | mJ |
| $t_{d(on)}$ | Inductive load, $T_J = 125^\circ\text{C}$ $I_C = I_{C90}$, $V_{GE} = 15\text{ V}$ $V_{CE} = 960\text{ V}$, $R_G = R_{off} = 100\ \Omega$ Remarks: Switching times may increase for V_{CE} (Clamp) $> 0.8\text{ V}_{CES}$, higher T_J or increased R_G | | 15 | ns | |
| t_{ri} | | | 30 | ns | |
| E_{on} | | | 0.5 | mJ | |
| $t_{d(off)}$ | | | 700 | ns | |
| t_{fi} | | | 1050 | ns | |
| E_{off} | | 7.7 | mJ | | |
| R_{thJC} | TO-220 | | 1.66 | KW | |
| R_{thCK} | | | 0.5 | KW | |



Min. Recommended Footprint
(Dimensions in inches and mm)

TO-220 AB Dimensions

TO-263 AA Outline


IXYS reserves the right to change limits, test conditions, and dimensions.

| | | | | | | | | |
|--|-----------|-----------|-----------|-----------|--------------|-------------|-------------|-----------|
| IXYS MOSFETs and IGBTs are covered by one or more of the following U.S. patents: | 4,835,592 | 4,931,844 | 5,049,961 | 5,237,481 | 6,162,665 | 6,404,065B1 | 6,683,344 | 6,727,585 |
| | 4,850,072 | 5,017,508 | 5,063,307 | 5,381,025 | 6,259,123B1 | 6,534,343 | 6,710,405B2 | 6,759,692 |
| | 4,881,106 | 5,034,796 | 5,187,117 | 5,486,715 | 6,306,728 B1 | 6,583,505 | 6,710,463 | |

Fig. 1. Output Characteristics
@ 25 °C

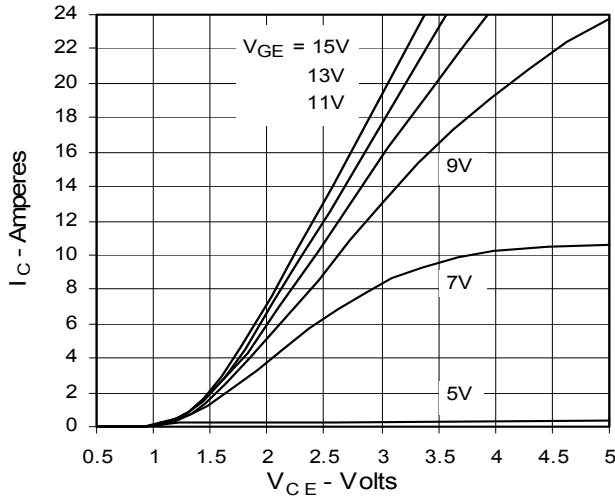


Fig. 2. Extended Output Characteristics
@ 25 °C

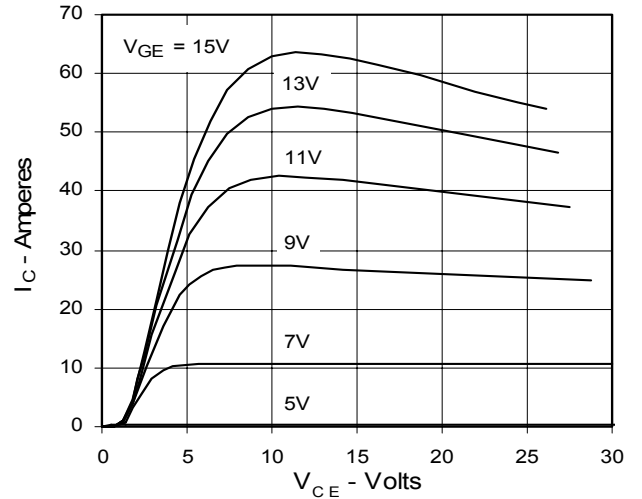


Fig. 3. Output Characteristics
@ 125 °C

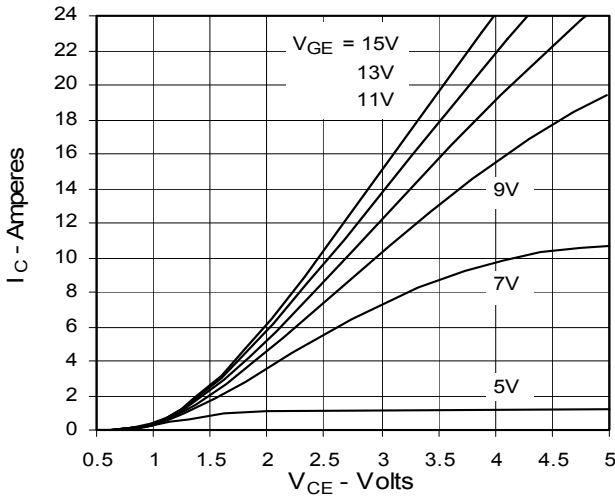


Fig. 4. Dependence of $V_{CE(sat)}$ on Temperature

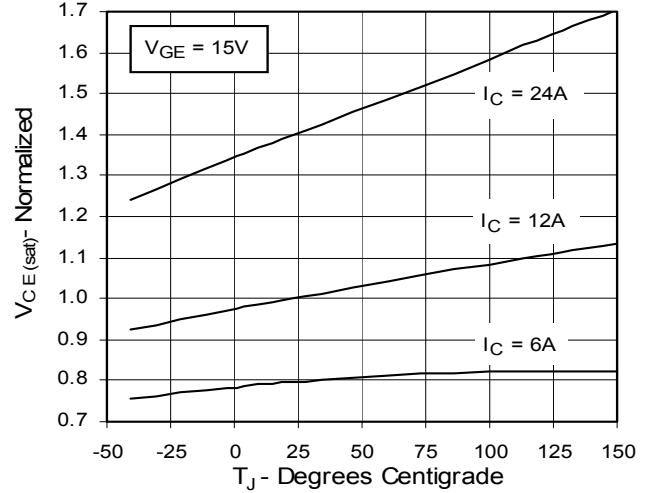


Fig. 5. Collector-to-Emitter Voltage vs. Gate-to-Emitter voltage

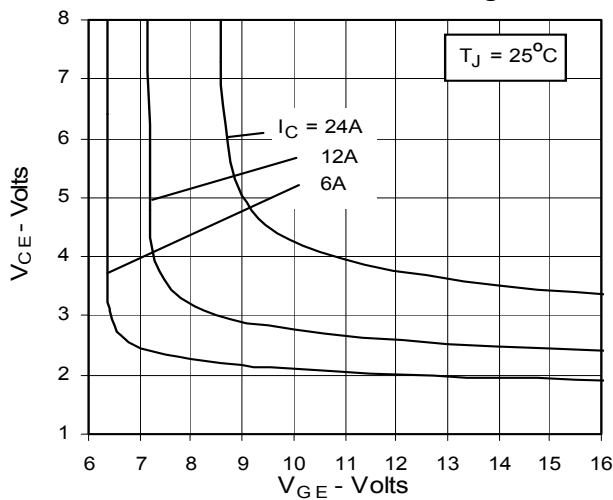


Fig. 6. Input Admittance

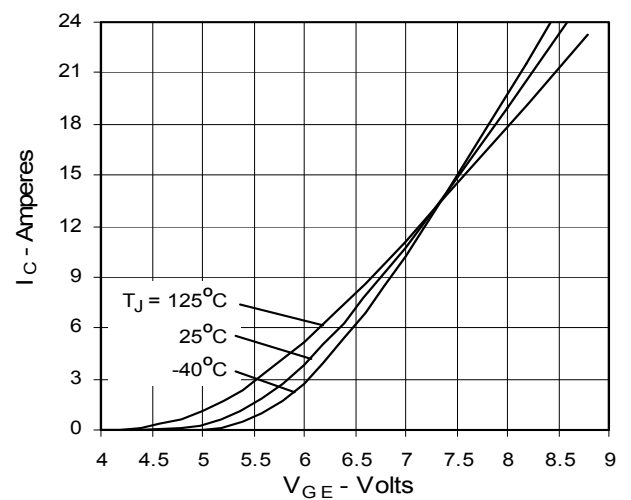


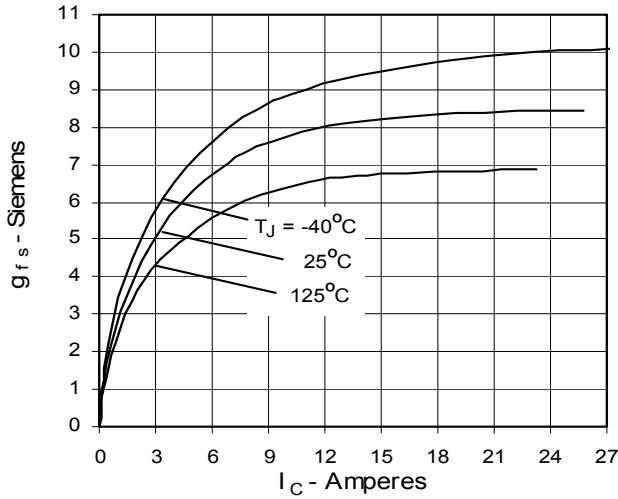
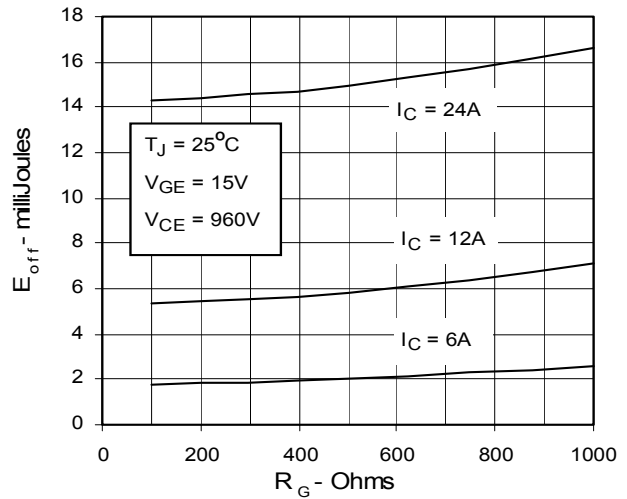
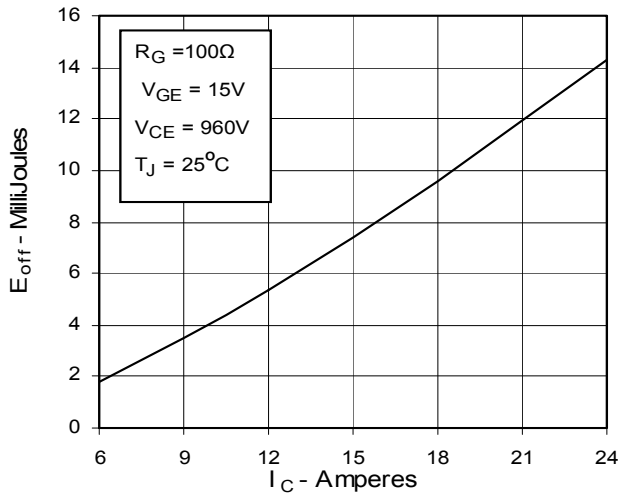
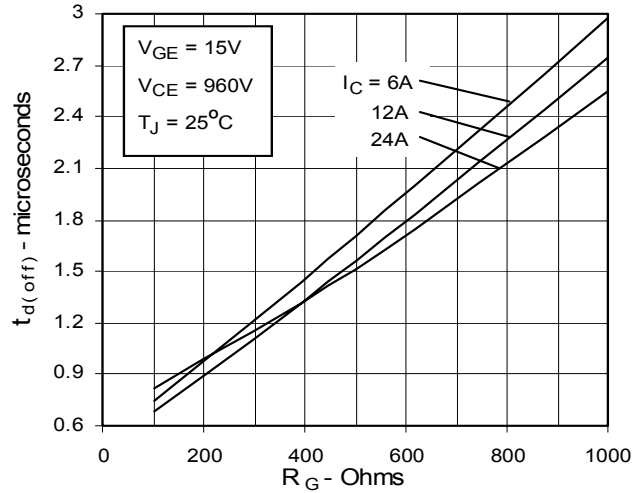
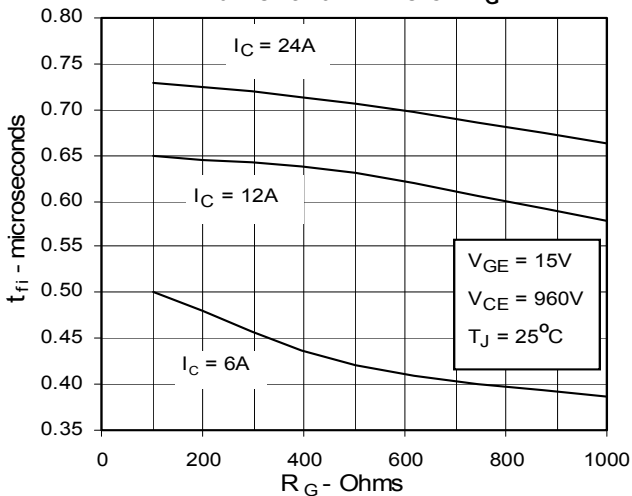
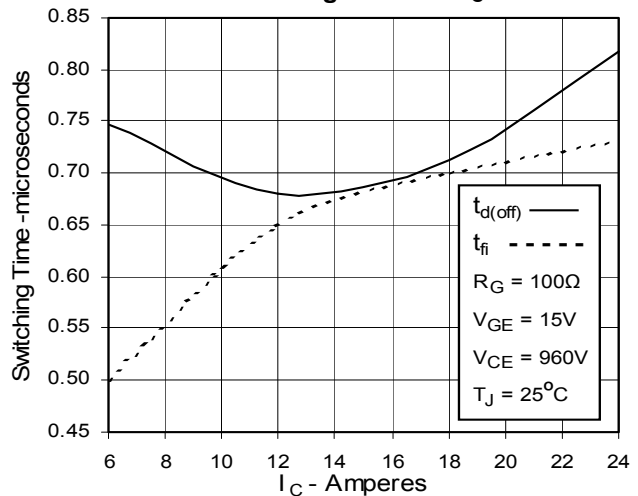
Fig. 7. Transconductance

Fig. 8. Dependence of Turn-off Energy Loss on R_G

Fig. 9. Dependence of Turn-Off Energy Loss on I_C

Fig. 10. Dependence of Turn-off Delay Time on R_G

Fig. 11. Dependence of Turn-off Current Fall Time on R_G

Fig. 12. Dependence of Turn-off Switching Time on I_C


Fig. 13. Gate Charge

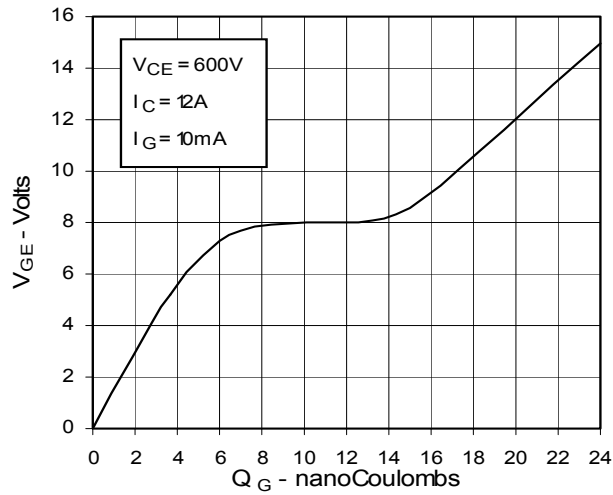


Fig. 14. Reverse-Bias Safe Operating Area

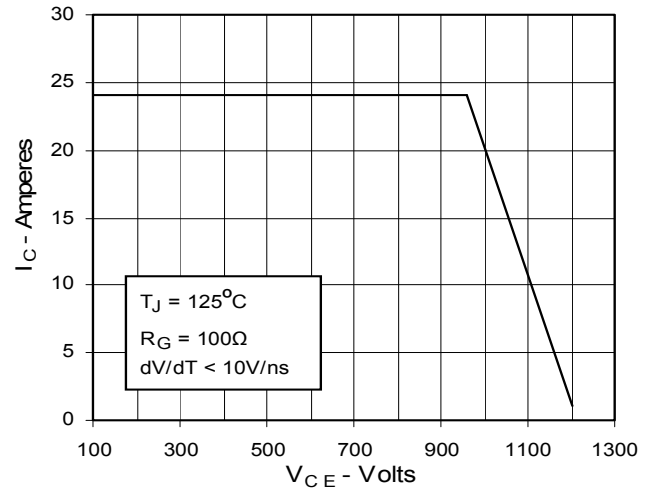


Fig. 15. Capacitance

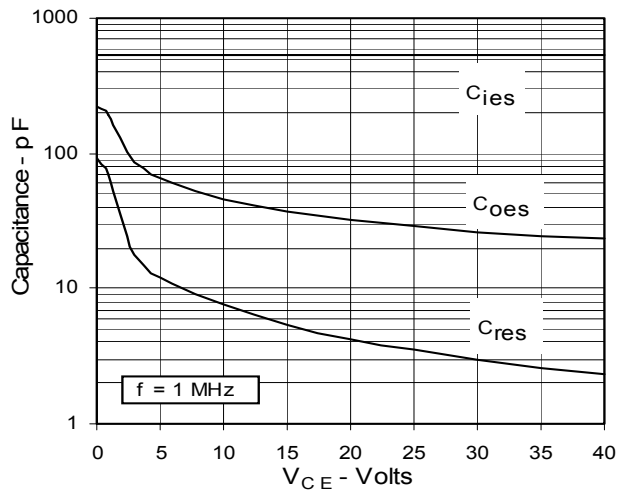


Fig. 17. Maximum Transient Thermal Resistance

